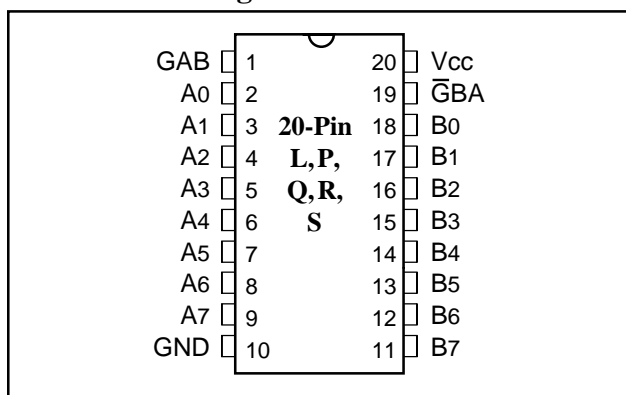


### Fast CMOS Octal Bus Transceiver (3-State)

#### Product Features

- PI74FCT623T is pin compatible with bipolar FAST™ Series at a higher speed and lower power consumption
- TTL input and output levels
- Extremely low static power
- Hysteresis on all inputs
- Industrial operating temperature range: -40°C to +85°C
- Packages available:
  - 20-pin 173 mil wide plastic TSSOP (L)
  - 20-pin 300 mil wide plastic DIP (P)
  - 20-pin 150 mil wide plastic QSOP (Q)
  - 20-pin 150 mil wide plastic TQSOP (R)
  - 20-pin 300 mil wide plastic SOIC (S)

#### Product Pin Configuration



#### Product Pin Description

Pin Name	Description
$\overline{\text{GBA}}$ , GAB	Enable Outputs
A0-A7	A Bus Inputs or 3-State Outputs
B0-B7	B Bus Inputs or 3-State Outputs
GND	Ground
Vcc	Power

#### Truth Table<sup>(1)</sup>

Inputs		Outputs
$\overline{\text{GBA}}$	GAB	
L	L	B Data to A Bus
H	H	A Data to B Bus
H	L	Z
L	H	B Data to A Bus A Data to B Bus

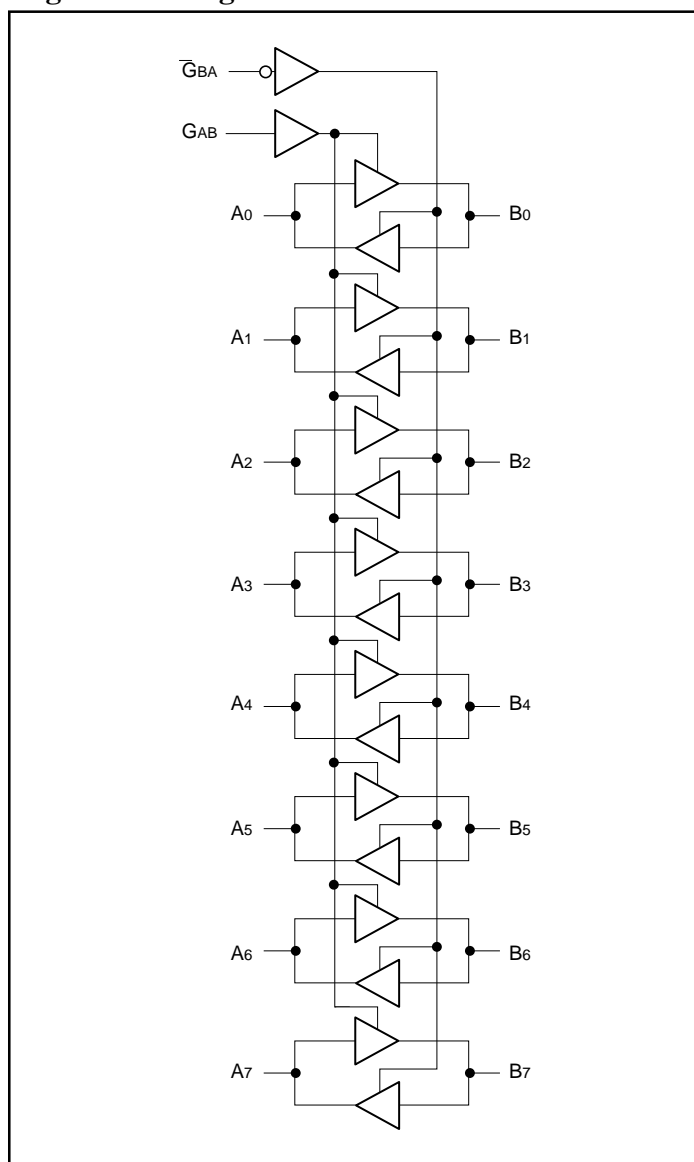
1. H = High Voltage Level  
L = Low Voltage Level  
Z = High Impedance (OFF) State

#### Product Description

Pericom Semiconductor's PI74FCT series of logic circuits are produced in the Company's advanced 0.6/0.8 micron CMOS technology, achieving industry leading speed grades.

The PI74FCT623T is an 8-bit wide non-inverting octal transceiver designed with 3-state bus-driving outputs in both the send and receive directions. Designed for asynchronous two-way operation between data buses, the control function allows for maximum flexibility in timing.

#### Logic Block Diagram



### Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature .....	-65°C to +150°C
Ambient Temperature with Power Applied .....	-40°C to +85°C
Supply Voltage to Ground Potential (Inputs & Vcc Only) .....	-0.5V to +7.0V
Supply Voltage to Ground Potential (Outputs & D/O Only) .....	-0.5V to +7.0V
DC Input Voltage .....	-0.5V to +7.0V
DC Output Current .....	120mA
Power Dissipation .....	0.5W

**Note:**

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

### DC Electrical Characteristics (Over the Operating Range, TA = -40°C to +85°C, VCC = 5V ± 5%)

Parameters	Description	Test Conditions <sup>(1)</sup>		Min.	Typ <sup>(2)</sup>	Max.	Units
VOH	Output HIGH Voltage	VCC = Min., VIN = VIH or VIL	IOH = -15.0 mA	2.4	3.0		V
VOL	Output LOW Current	VCC = Min., VIN = VIH or VIL	IOL = 64 mA		0.3	0.55	V
VIH	Input HIGH Voltage	Guaranteed Logic HIGH Level		2.0			V
VIL	Input LOW Voltage	Guaranteed Logic LOW Level				0.8	V
IiH	Input HIGH Current	VCC = Max.	VIN = VCC			1	µA
IiL	Input LOW Current	VCC = Max.	VIN = GND			-1	µA
IOZH	High Impedance	VCC = Max.	VOUT = 2.7V			1	µA
IOZL	Output Current		VOUT = 0.5V			-1	µA
VIK	Clamp Diode Voltage	VCC = Min., IIN = -18 mA			-0.7	-1.2	V
Ios	Short Circuit Current	VCC = Max. <sup>(3)</sup> , VOUT = GND		-60	-120		mA
IOFF	Power Down Disable	VCC = GND, VOUT = 4.5V		—	—	100	µA
VH	Input Hysteresis				200		mV

### Capacitance (TA = 25°C, f = 1 MHz)

Parameters <sup>(4)</sup>	Description	Test Conditions	Typ	Max.	Units
CIN	Input Capacitance	VIN = 0V	6	10	pF
COUT	Output Capacitance	VOUT = 0V	8	12	pF

**Notes:**

1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at VCC = 5.0V, +25°C ambient and maximum loading.
3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
4. This parameter is determined by device characterization but is not production tested.

**Power Supply Characteristics**

Parameters	Description	Test Conditions <sup>(1)</sup>		Min.	Typ <sup>(2)</sup>	Max.	Units
I <sub>CC</sub>	Quiescent Power Supply Current	V <sub>CC</sub> =Max.	V <sub>IN</sub> =GND or V <sub>CC</sub>		0.1	500	μA
ΔI <sub>CC</sub>	Supply Current per Input @ TTLHIGH	V <sub>CC</sub> =Max.,	V <sub>IN</sub> =3.4V <sup>(3)</sup>		0.5	2.0	mA
I <sub>CCD</sub>	Supply Current per Input per MHz <sup>(4)</sup>	V <sub>CC</sub> = Max., Outputs Open G <sub>BA</sub> =G <sub>AB</sub> =GND, One Input Toggling, 50% Duty Cycle	V <sub>IN</sub> = V <sub>CC</sub> V <sub>IN</sub> =GND		0.15	0.25	mA/ MHz
I <sub>C</sub>	Total Power Supply Current <sup>(6)</sup>	V <sub>CC</sub> = Max., Outputs Open f <sub>CP</sub> = 10 MHz, 50% Duty Cycle G <sub>BA</sub> = G <sub>AB</sub> = GND, 50% Duty Cycle One Bit toggling at f <sub>i</sub> = 5 MHz	V <sub>IN</sub> = V <sub>CC</sub> V <sub>IN</sub> = GND		1.5	3.5 <sup>(5)</sup>	mA
			V <sub>IN</sub> = 3.4V V <sub>IN</sub> = GND		1.8	4.5 <sup>(5)</sup>	
		V <sub>CC</sub> = Max., Outputs Open f <sub>CP</sub> = 10 MHz, 50% Duty Cycle G <sub>BA</sub> = G <sub>AB</sub> = GND, 50% Duty Cycle Eight Bits toggling at f <sub>i</sub> = 2.5 MHz 50% Duty Cycle	V <sub>IN</sub> = V <sub>CC</sub> V <sub>IN</sub> = GND		3.0	6.0 <sup>(5)</sup>	
			V <sub>IN</sub> = 3.4V V <sub>IN</sub> = GND		5.0	14.0 <sup>(5)</sup>	

**Notes:**

- For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device.
- Typical values are at V<sub>CC</sub> = 5.0V, +25°C ambient.
- Per TTL driven input (V<sub>IN</sub> = 3.4V); all other inputs at V<sub>CC</sub> or GND.
- This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
- Values for these conditions are examples of the I<sub>CC</sub> formula. These limits are guaranteed but not tested.
- I<sub>C</sub> = I<sub>QUIESCENT</sub> + I<sub>INPUTS</sub> + I<sub>DYNAMIC</sub>  
 $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_i N_i)$   
 I<sub>CC</sub> = Quiescent Current  
 ΔI<sub>CC</sub> = Power Supply Current for a TTL High Input (V<sub>IN</sub> = 3.4V)  
 D<sub>H</sub> = Duty Cycle for TTL Inputs High  
 N<sub>T</sub> = Number of TTL Inputs at D<sub>H</sub>  
 I<sub>CCD</sub> = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)  
 f<sub>CP</sub> = Clock Frequency for Register Devices (Zero for Non-Register Devices)  
 f<sub>i</sub> = Input Frequency  
 N<sub>i</sub> = Number of Inputs at f<sub>i</sub>  
 All currents are in milliamps and all frequencies are in megahertz.

**Switching Characteristics over Operating Range**

Parameters	Description	Conditions <sup>(1)</sup>	623T		623AT		623CT		Units
			Com.		Com.		Com.		
			Min	Max	Min	Max	Min	Max	
t <sub>PLH</sub>	Propagation Delay	C <sub>L</sub> = 50 pF R <sub>L</sub> = 500Ω	15	75	15	55	15	4.8	ns
t <sub>PHL</sub>	A <sub>N</sub> to B <sub>N</sub>								
t <sub>PLH</sub>	Propagation Delay		15	75	15	55	15	4.8	
t <sub>PHL</sub>	B <sub>N</sub> to A <sub>N</sub>								
t <sub>PZH</sub>	Output Enable Time		15	9.0	15	7.0	15	6.1	
t <sub>PZL</sub>	G <sub>BA</sub> to A <sub>N</sub>								
t <sub>PZH</sub>	Output Disable Time <sup>(3)</sup>		15	8.0	15	6.5	15	5.6	
t <sub>PZL</sub>	G <sub>BA</sub> to A <sub>N</sub>								
t <sub>PZH</sub>	Output Enable Time	15	9.0	15	7.0	15	6.1	ns	
t <sub>PZL</sub>	G <sub>AB</sub> to B <sub>N</sub>								
t <sub>PZH</sub>	Output Disable Time <sup>(3)</sup>	15	8.0	15	6.5	15	5.6	ns	
t <sub>PZL</sub>	G <sub>AB</sub> to B <sub>N</sub>								

**Notes:**

- See test circuit and wave forms.
- Minimum limits are guaranteed but not tested on Propagation Delays.
- This parameter is guaranteed but not production tested.